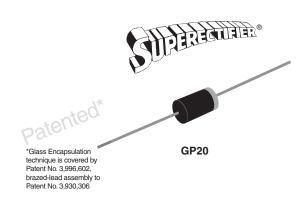
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# EGP50A thru EGP50G

Vishay General Semiconductor

# **Glass Passivated Ultrafast Rectifier**



**PRIMARY CHARACTERISTICS** 

I<sub>F(AV)</sub>

V<sub>RRM</sub>

I<sub>FSM</sub>

t<sub>rr</sub>

VF

T<sub>.1</sub> max.

5.0 A

50 V to 400 V

150 A

50 ns

0.95 V, 1.25 V

150 °C

### **FEATURES**

- · Cavity-free glass-passivated junction
- · Ultrafast reverse recovery time
- · Low forward voltage drop
- Low leakage current
- Low switching losses, high efficiency
- High forward surge capability
- Solder dip 260 °C, 40 s
- · Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

#### **TYPICAL APPLICATIONS**

For use in high frequency rectification and freewheeling application in switching mode converters inverters for and consumer, computer and telecommunication.

#### **MECHANICAL DATA**

Case: GP20, molded epoxy over glass body

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 gualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)									
PARAMETER	SYMBOL	EGP50A	EGP50B	EGP50C	EGP50D	EGP50F	EGP50G	UNIT	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	150	200	300	400	V	
Maximum RMS voltage	V <sub>RMS</sub>	35	70	105	140	210	280	V	
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	150	200	300	400	V	
Maximum average forward rectified current 0.375" (9.5 mm) lead length at $T_L = 55$ °C	I <sub>F(AV)</sub>	(AV) 5						A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	150						A	
Operating and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	T <sub>J</sub> , T <sub>STG</sub> - 65 to + 150						°C	

## Revision: 20-Aug-07





RoHS

COMPLIANT

### Vishay General Semiconductor



<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25$ °C unless otherwise noted)										
PARAMETER	TEST CONDITIONS		SYMBOL	EGP50A	EGP50B	EGP50C	EGP50D	EGP50F	EGP50G	UNIT
Maximum instantaneous forward voltage	5.0 A V <sub>F</sub>		V <sub>F</sub>	0.95			1.25		V	
Maximum DC reverse current at rated DC blocking voltage		T <sub>A</sub> = 25 °C T <sub>A</sub> = 125 °C	I <sub>R</sub>	R 5.0 50					μΑ	
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		t <sub>rr</sub>	50					ns	
Typical junction capacitance	4.0 V, 1	MHz	CJ	95		7	5	pF		

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER	SYMBOL	EGP50A	EGP50B	EGP50C	EGP50D	EGP50F	EGP50G	UNIT
Typical thermal resistance <sup>(1)</sup>	$R_{ heta JA}$ $R_{ heta JL}$	20 5.0					°C/W	

#### Note:

(1) Thermal resistance from junction to ambient, and from junction to lead at 0.375" (9.5 mm) lead length, P.C.B. mounted

ORDERING INFORMATION (Example)								
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
EGP50G-E3/54	1.01	54	1400	13" diameter paper tape and reel				
EGP50G-E3/73	1.01	73	1000	Ammo pack packaging				
EGP50GHE3/54 (1)	1.01	54	1400	13" diameter paper tape and reel				
EGP50GHE3/73 <sup>(1)</sup>	1.01	73	1000	Ammo pack packaging				

Note:

(1) Automotive grade AEC Q101 qualified

### **RATINGS AND CHARACTERISTICS CURVES**

 $(T_A = 25 \ ^{\circ}C \text{ unless otherwise noted})$ 

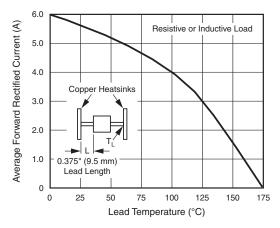


Figure 1. Maximum Forward Current Derating Curve

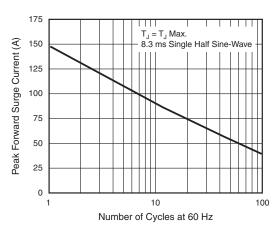


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

For technical questions within your region, please contact one of the following: <u>PDD-Americas@vishay.com</u>, <u>PDD-Asia@vishay.com</u>, <u>PDD-Europe@vishay.com</u>



## EGP50A thru EGP50G

### Vishay General Semiconductor

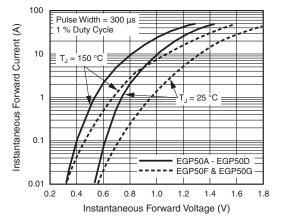


Figure 3. Typical Instantaneous Forward Characteristics

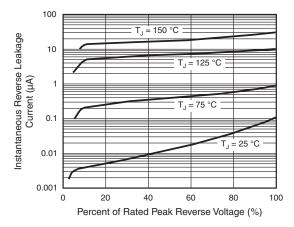


Figure 4. Typical Reverse Leakage Characteristics

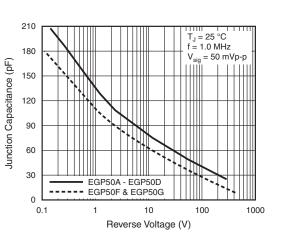


Figure 5. Typical Junction Capacitance

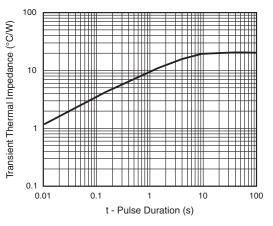
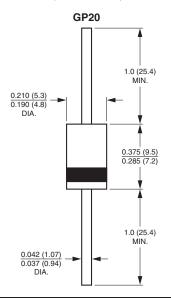


Figure 6. Typical Transient Thermal Impedance

#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



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Vishay

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